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Information Disclosure Statement by Applicant		Applicant: John M. Caywood	
(Use several sheets if necessary)		Filed: 8/28/2001 Group: (to be assigned) 2819	

U.S. Patent Documents

Init.	Document No.	Date	Name	Class	Subclass	Filing Date
A	3,778,645	12/11/73	Mattauch et al.	307	318	1/31/72
B	4,035,820	7/12/77	Matzen	357	23	12/29/75
C	4,037,242	7/19/77	Gosney	357	23	12/29/75
D	4,513,397	4/23/85	Ipri et al.	365	185	12/10/82
E	4,626,887	12/2/86	Schmitt-Landsiedel et al.	357	43	8/2/84
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G	4,686,558	8/11/87	Adam	357	42	9/1/83
H	4,752,912	6/21/88	Guterman	365	185	7/22/85
I	4,907,197	3/6/90	Uchida	365	185	7/12/88
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K	4,910,565	3/20/90	Masuoka	357	23.5	5/12/88
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Foreign Documents

Translation

Init.	Document No.	Date	Country	Class	Subclass	Yes	No
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Other References (Including Author, Title, Date, Pertinent Pages, etc.)	
Y	Dons, et al., "Direct Tunneling Diode Structure with a Multi-Layer Charge Injection Barrier", <i>29th IEEE Semiconductor Interface Specialists Conference</i> (1998)
Z	Guo, Xin, "Tunneling Leakage Current in Oxynitride: Dependence on Oxygen/Nitrogen Content", <i>IEEE, Electron Device Letters</i> , Vol. 19, No. 6, pp. 207-209 (1998)
AA	Huber et al, "Hot-Electron Transport in Al-Al ₂ O ₃ Triodes Produced by Plasma Oxidation", <i>Journal of Applied Physics</i> , Vol. 39, No. 11, pp. 5104-5116 (1968)
BB	Krolikowski, "Photoemission Studies of the Noble Metals. I. Copper", <i>Physical Review</i> , Vol. 185, No. 3, pp. 882-900 (1969)
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DD	Mead, "Operation of Tunnel-Emission Devices", <i>J. Appl. Phys.</i> , Vol. 32, No. 4 (1961)
EE	Mead, "The Tunnel-Emission Amplifier", <i>Proceedings of IRE</i> , pp. 359-361 (1960)
Examiner	Date Considered 3/31/04

Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include a copy of this form with the next communication to applicant.